

$^{58}\text{Ni}(^{32}\text{S},\text{pn})$ [1996Od01](#)

Type	Author	History	Citation	Literature Cutoff Date
Full Evaluation	E. A. Mccutchan and A. A. Sonzogni		NDS 115, 135 (2014)	1-Nov-2013

$E(^{32}\text{S})=100, 101, \text{ and } 105 \text{ MeV}$. Measured $E\gamma$, $I\gamma$, $\gamma\gamma$ and $\gamma\beta$ coincidences, $T_{1/2}$ using two HPGe detectors and one LEPS detector. Channel selection performed with a tape transport system and a rotation disk. Also [1993OdZY](#), [1995ShZX](#).

 ^{88}Tc Levels

<u>E(level)</u>	<u>J^π[†]</u>	<u>$T_{1/2}$[‡]</u>
x	(5 ⁺ ,6 ⁺ ,7 ⁺)	6.4 s 8
y	(2 ⁺ ,3 ⁺)	5.8 s 2

[†] From the Adopted Levels.

[‡] From $\gamma(t)$ ([1996Od01](#)).